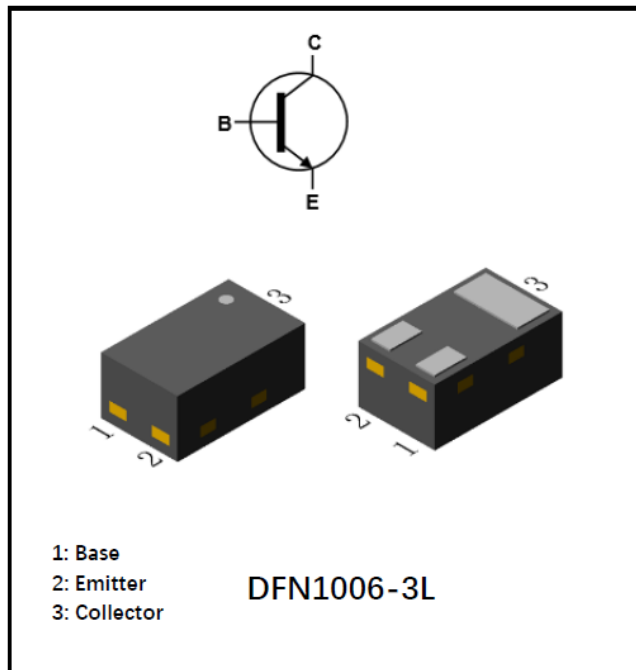


NPN General Purpose Transistor



Features

- Lead Free Finish/
- Small package saves board space
- Moisture Sensitivity Level 3

Mechanical Data

- **Package:** DFN1006-3L
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Marking:** D5

■Maximum Ratings ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

Symbol	Parameter	Value	Unit
VCBO	Collector-Base Voltage	50	V
VCEO	Collector-Emitter Voltage	45	V
VEBO	Emitter-Base Voltage	6	V
IC	Collector Current	100	mA
PC	Collector Power Dissipation	100	mW
Tj	Junction Temperature	-55~+150	°C
Tstg	Storage Temperature	-55~+150	°C

■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
BC847BM	Approximate 0.89	10K	100K	400K	Tape & Reel

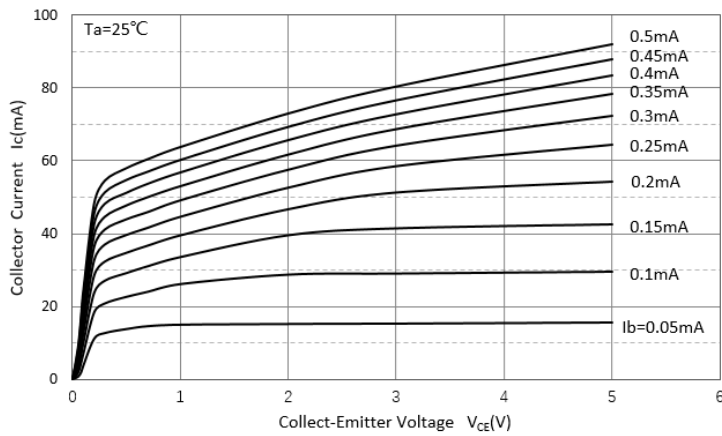
BC847BM

■Electrical Characteristics (T_a=25℃ Unless otherwise specified)

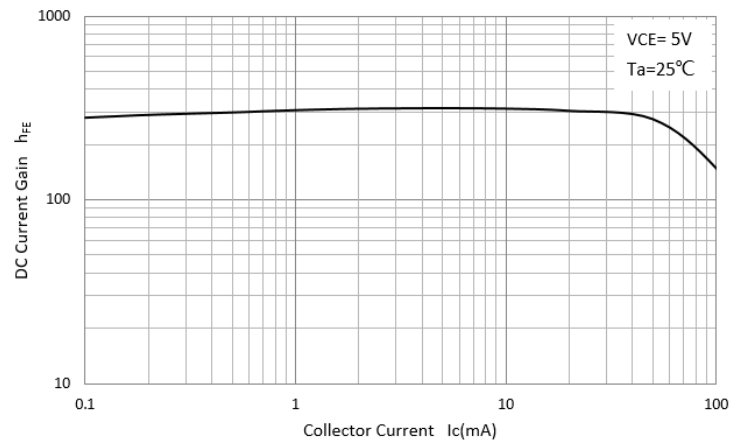
Parameter	Symbol	Test conditions	Min	TYP	Max	Unit
Collector-base breakdown voltage	V _{CBO}	IC= 10μA, IE=0	50	-	-	V
Collector-emitter breakdown voltage	V _{CEO}	IC= 10mA, IB=0	45	-	-	V
Emitter-base breakdown voltage	V _{EBO}	IE= 10μA, IC=0	6	-	-	V
Collector-base cut-off current	I _{CBO}	VCB=30 V ,IE=0	-	-	15	nA
Emitter-base cut-off current	I _{EBO}	VEB=5 V , IC=0	-	-	100	nA
DC current gain	h _{FE}	VCE= 5V, IC= 2mA	200	-	450	
Collector-emitter saturation voltage	V _{CE(sat)}	IC=10mA, IB= 0.5mA	-	-	200	mV
	V _{CE(sat)}	IC=100mA, IB= 5mA	-	-	400	mV
Base-emitter saturation voltage	V _{BE(sat)}	IC=100mA, IB= 5mA	-	0.9	1.1	V
Base-emitter voltage	V _{BE}	VCE= 5V, IC= 2mA	580	-	700	mV
	V _{BE}	VCE=5V, IC= 10mA	-	-	770	mV
Transition frequency	f _T	VCE=5V, IC= 10mA f=100MHz	100	-	-	MHz
Collector-base output capacitance	Cob	VCB=10V,f=1MHz	-	-	4.5	pF

■ Characteristics (Typical)

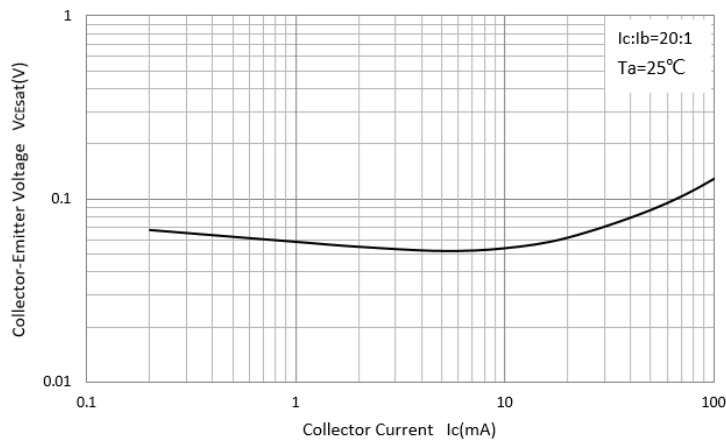
Static Characteristic



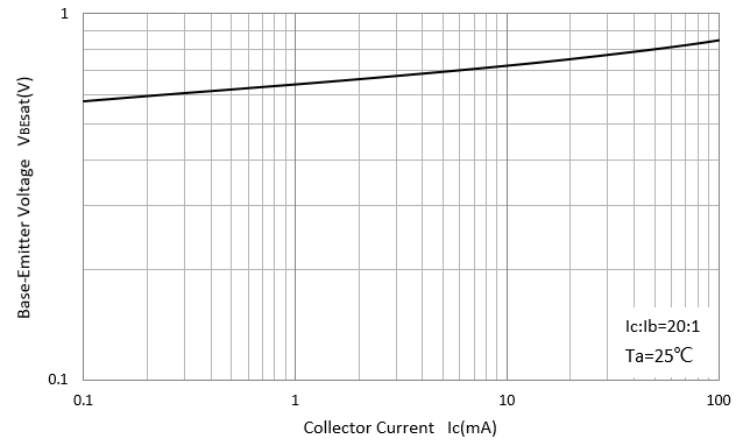
DC Current Gain



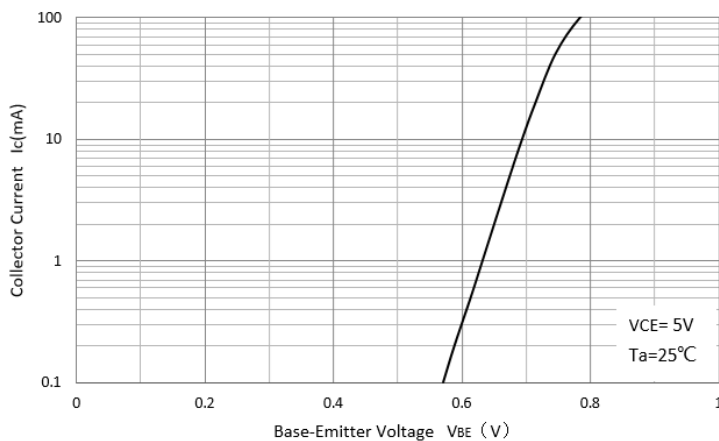
Collector-Emitter Saturation Voltage



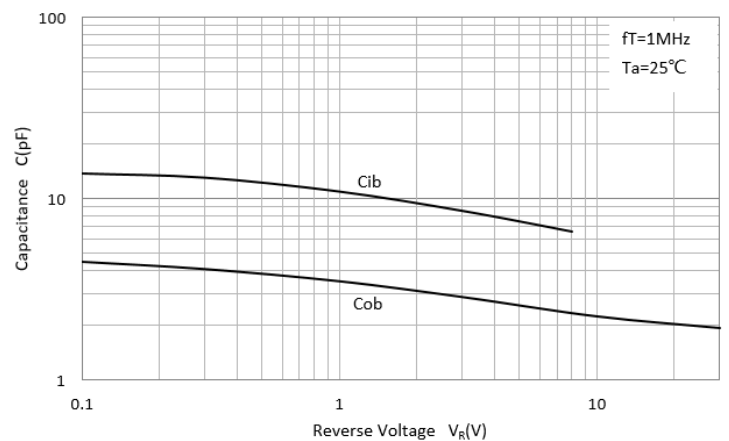
Base-Emitter Saturation Voltage



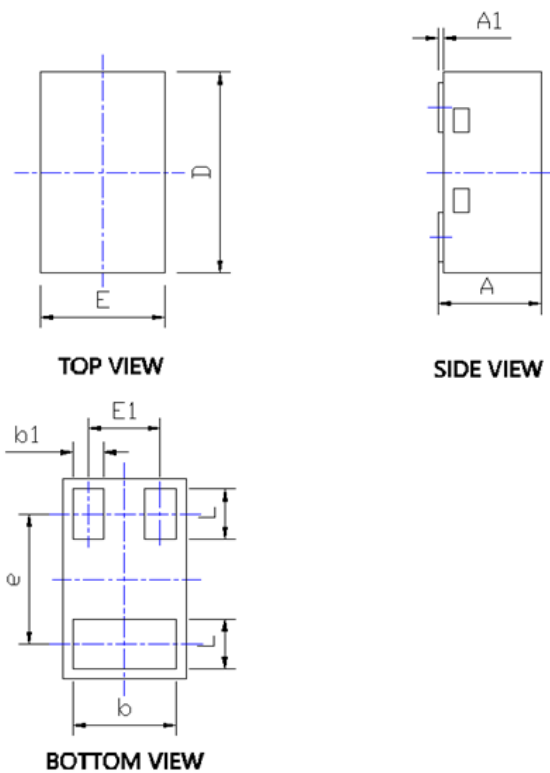
Base-Emitter On Voltage



$C_{ob}/C_{ib}-V_{CB}/V_{EB}$

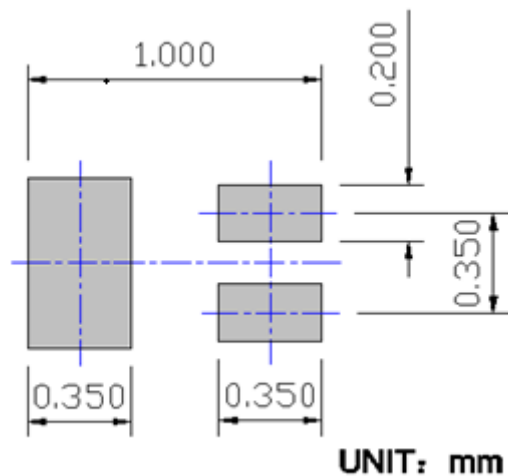


■ Outline Dimensions



SYMBOL	DIMENSIONS		
	Millimeter		
	MIN.	NOM.	MAX.
A	0.42	---	0.55
A1	0.025REF		
b	0.45	0.50	0.55
b1	0.10	0.15	0.20
D	0.95	1.00	1.05
E	0.55	0.60	0.65
E1	0.35BSC		
e	0.65BSC		
L	0.20	0.25	0.30

■ Soldering Footprint



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